



isc Silicon NPN Power Transistor

DESCRIPTION

- High Collector Current:: Ic= 20A
- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 0.4V(Max)@I_C= 8A
- · Complement to Type 2SB904
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

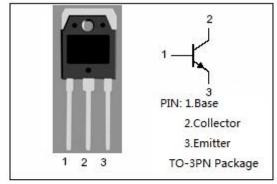


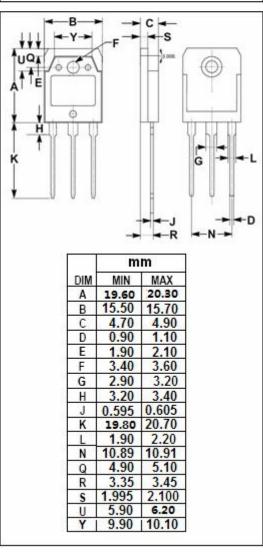
APPLICATIONS

 Designed for large current switching of relay drivers, high-speed inverters, converters applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	60	V
Vceo	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	20	Α
Ісм	Collector Current-Peak 30		Α
P _C	Total Power Dissipation @ T _C =25°C	60	W
	Total Power Dissipation @ T _a =25℃	2.5	VV
TJ	Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$







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2SD1213

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA; R _{BE} = ∞	30			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 0.4A			0.4	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 40V; I _E = 0			0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			0.1	mA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 2V	70		280	
h _{FE-2}	DC Current Gain	I _C = 10A; V _{CE} = 2V	30			
f _T	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 5V		120		MHz
Switching times						
ton	Turn-on Time	7		0.3		μ S
t _{stg}	Storage Time	$R_L = 1 \Omega$, $V_{CC} = 10V$ $I_C = 10A$; $I_{B1} = I_{B2} = 0.5A$		0.6		μS
t _f	Fall Time	, , , -		0.02		μ S

♦ h_{FE-1} Classifications

Q	R	S
70-140	100-200	140-280

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